# 2SA893, 2SA893A

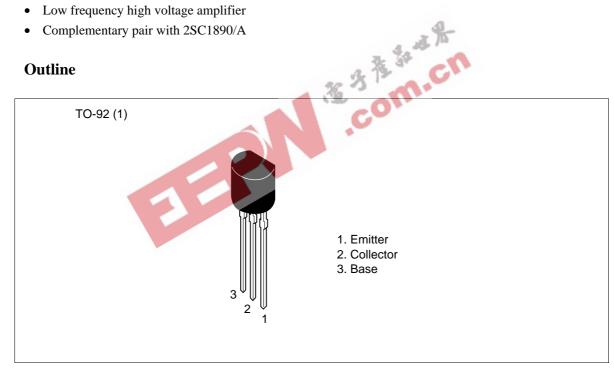
Silicon PNP Epitaxial

# **HITACHI**

### **Application**

- Low frequency high voltage amplifier
- Complementary pair with 2SC1890/A

#### **Outline**





## 2SA893, 2SA893A

## **Absolute Maximum Ratings** (Ta = 25°C)

Item	Symbol	2SA893	2SA893A	Unit
Collector to base voltage	$V_{\scriptscriptstyle \sf CBO}$	-90	-120	V
Collector to emitter voltage	V <sub>CEO</sub>	-90	-120	V
Emitter to base voltage	$V_{EBO}$	<b>-</b> 5	<b>–</b> 5	V
Collector current	I <sub>c</sub>	<b>-</b> 50	<b>–</b> 50	mA
Collector power dissipation	P <sub>c</sub>	300	300	mW
Junction temperature	Tj	150	150	°C
Storage temperature	Tstg	-55 to +150	-55 to +150	°C

## **Electrical Characteristics** (Ta = 25°C)

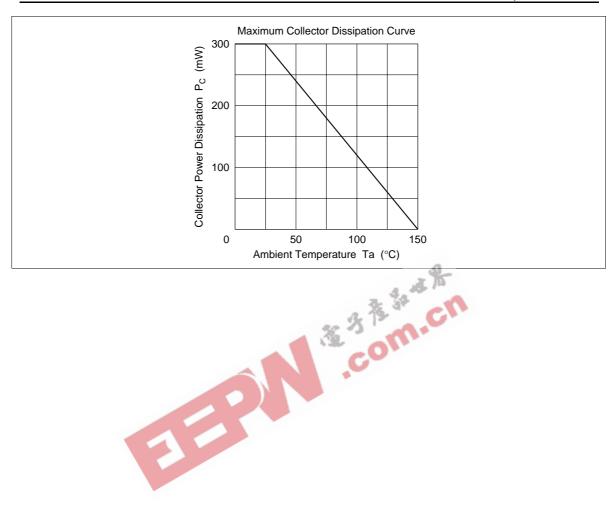
<b>Electrical Characteristics</b> (Ta = 25°C)									
		2SA893		2SA893A					
Item	Symbol	Min	Тур	Max	Min	Тур	Max	Unit	Test conditions
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	-90			-120	<b>,</b> O,		V	$I_{C} = -1 \text{ mA}, R_{BE} = \infty$
Collector cutoff current	I <sub>CBO</sub>		7	-0.5	_	_	_	μΑ	$V_{CB} = -75 \text{ V}, I_{E} = 0$
			$\angle$	_	_	_	-0.5	$\mu A$	$V_{CB} = -100 \text{ V}, I_{E} = 0$
DC current transfer ratio	h <sub>FE</sub> *1	250	_	800	250	_	800		$V_{CE} = -12 \text{ V},$ $I_C = -2 \text{ mA}$
Base to emitter voltage	V <sub>BE</sub>	_	_	-0.75	_	_	-0.75	V	$V_{CE} = -12 \text{ V},$ $I_C = -2 \text{ mA}$
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	_	_	-0.5	_	_	-0.5	V	$I_{C} = -10 \text{ mA},$ $I_{B} = -1 \text{ mA}$
Gain bandwidth product	f <sub>T</sub>	_	120	_	_	120	_	MHz	$V_{CE} = -12 \text{ V},$ $I_{C} = -2 \text{ mA}$
Collector output capacitance	Cob	_	1.8	_	_	1.8	_	pF	$V_{CB} = -25 \text{ V}, I_{E} = 0,$ f = 1 MHz
Noise figure	NF	_	2	10	_	2	10	dB	$V_{CE} = -6 \text{ V},$ $I_{C} = -50  \mu\text{A}$ $R_{g} = 50  k\Omega,  f = 1  k\text{Hz}$

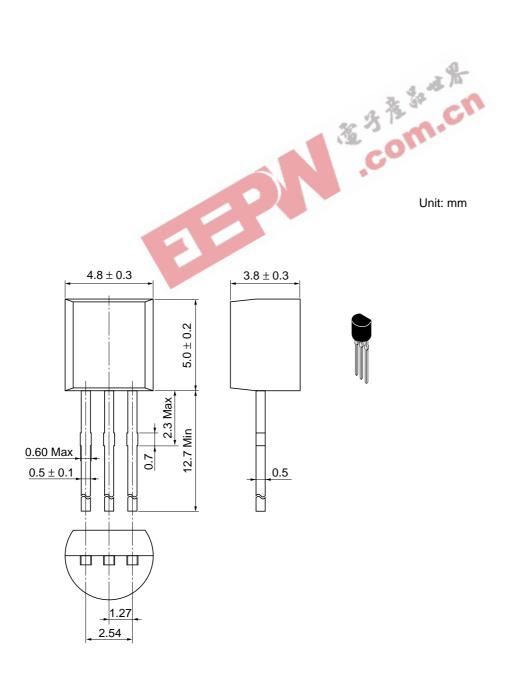
Note: 1. The 2SA893/A is grouped by h<sub>FE</sub> as follows.

D	E
250 to 500	400 to 800

See characteristic curves of 2SA872 and 2SA872A

# 2SA893, 2SA893A





Hitachi Code	TO-92 (1)
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.25 a

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